## Colossalm agnetoresistance without phase separation: Disorder-induced spin glass state and nanom eter scale orbital-charge correlation in half doped manganites

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The magnetic and electrical properties of high quality single crystals of A -site disordered (solid solution)  $Ln_{0:5}Ba_{0:5}M nO_3$  are investigated near the phase boundary between the spin glass insulator and colossalm agnetoresistive ferrom agnetic metal, locating near Ln = Sm. The temperature dependence of the ac-susceptibility and the x-ray di use scattering of  $Eu_{0:5}Ba_{0:5}M nO_3$  are analyzed in detail. The uniform ity of the random potential perturbation in  $Ln_{0:5}Ba_{0:5}M nO_3$  crystals with sm all bandwidth yields, rather than the phase separation, an hom ogeneous short ranged charge/orbital order which gives rise to a nearly-atom ic spin glass state. Rem arkably, this m icroscopically disordered CE-glass" state alone is able to bring forth the colossalm agnetoresistance.

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The phase diagram of colossalm agnetoresistive (CMR) perovskite m anganites, as well as m any strongly correlated electron systems, is multicritical, involving com peting spin, charge/orbital, and lattice orders[1, 2]. For example in the half-doped  $Ln_{0.5}Ba_{0.5}M nO_3$  (Ln being a rare earth cation), the charge/orbital ordered (CO/OO)insulating (favored by sm all Ln cations) and ferrom agnetic (FM) metallic (larger Ln cations) states compete with each other, and bicritically m eet near Ln = Nd[3]. The meeting point is actually multicritical, as the Atype antiferrom agnetic (AFM) instability also exists[3]. In the presence of quenched disorder, namely when the perovskite A -sites are solid solution of Ln and Ba (term ed \A-site disorder"), the phase diagram becom es asym m etric. The FM phase transition is still observed near the critical point, even though the Curie tem perature  $T_c$  is steeply diminished. The long-range CO/OO state is, on the other hand, completely suppressed and only shortrange CO/OO correlation is observed. This phase corresponds in the spin sector to a spin glass (SG) state, which, as we will show in this article, is not related to som em acroscopic phase separation [4, 5], but results from the frustration and magnetic disorderm icroscopically introduced within this \CE-glass" [6] state. The degree of quenched disorder can be controlled by modifying the m ism atch of the constituent A-site cations[7]. Recent pressure experim ents show that the asym m etric phase diagram of disordered Ln<sub>0:5</sub>Ba<sub>0:5</sub>M nO<sub>3</sub> (LnBM O) is solely determ ined by the bandwidth W variation, for a xed degree of disorder [8]. It thus in plies that quenched disorder a ects the CO/OO phase m ore aggressively than the FM state. These experimental ndings could be accounted for by the theoretical model considering multicritical uctuations between the FM and CO /OO phases[9], in presence of disorder. The calculations also predict an enhanced electronic localization above T<sub>c</sub> near the critical region, suggesting that large CMR e ects m ay em erge [9].

W e thus investigate the magnetic and electrical properties of high-quality single crystals of A -site disordered Ln<sub>0:5</sub>Ba<sub>0:5</sub>MnO<sub>3</sub>, around the SG insulator/FM metal phase boundary (near Ln = Sm). The temperature T and frequency f dependence of the ac-susceptibility of  $Eu_{0:5}Ba_{0:5}MnO_3$  (Ln = Eu, EBMO) is analyzed in detail. The low-temperature EBM 0 resembles canonical spin glasses, and characteristic phenom ena such as aging, m em ory, and rejuvenation are observed at low tem peratures. This spin glass state, and thus the shortrange orbital-order revealed by the x-ray di use scattering, appear hom ogeneous down to the nanom eter scale. This suggests that, in Ln<sub>0:5</sub>Ba<sub>0:5</sub>M nO<sub>3</sub> crystals with relatively small bandwidth, the e ect of the disorder is m icroscopic, and does not induce the phase separation. The observed \CE-glass" state appears to contain all the building blocks for the colossal magnetoresistance phenom enon.

Single crystals of A-site disordered Ln<sub>0:5</sub>Ba<sub>0:5</sub>M nO<sub>3</sub> (Ln = Eu, Sm, Nd, Pr, and La) were grown by the oating zone m ethod [3]. The phase-purity of the crystals and the perfect disorder (solid solution) of the Ln/Ba cations on the A-site was checked by x-ray di raction [3]. Single crystal x-ray di raction was perform ed at selected tem peratures from 300 K down to 30 K using an imaging plate system equipped with a closed cycle helium refrigerator. The magnetization and ac-susceptibility (T;! = 2 f) data were recorded on a MPM SXL SQUID magnetom eter equipped with the ultra low - eld option (low frequencies) and a PPM S6000 (higher frequencies), after carefully zeroing or compensating the background magnetic elds of the system s. Additional phase corrections were perform ed for som e frequencies. The transport properties were measured using a standard four-probe method.

Figure 1 shows the asymmetric phase diagram of the A-site disordered LnBMO using lled symbols. Results for the A-site ordered samples[3] are shown using open symbols for comparison. For large cations, the FM phase remains, albeit with reduced  $T_c$ . The  $T_c$  is steeply suppressed, as the Ln ion size decreases. For smaller Ln cations, a spin glass phase with non-equilibrium dynam-ics emerges. The inset of Fig. 1 shows the resistivity of the samples with Ln = Eu, Sm, Nd, and La measured in zero and applied magnetic eld.  $Eu_{0.5}Ba_{0.5}M nO_3$  and  $Sm_{0.5}Ba_{0.5}M nO_3$  (SBMO) show insulator-like resistivity in 0 and 7 T; larger magnetic elds may be required to induce m etallicity and magnetoresistance.



FIG.1: (color online) E lectronic phase diagram for the A-site ordered and disordered  $Ln_{0:5}Ba_{0:5}M$  nO<sub>3</sub> as a function of the ionic radius of Ln. Ln = Eu, Sm, Sm<sub>1</sub>  $_{y}Nd_{y}$  (y = 0.5, 0.8), Nd, Pr, and La, reproduced from Ref. 3. For the Ln/Ba ordered compounds, the AFM transitions below  $T_{c}$  (A-type AFM; Ln = Nd and Pr) and  $T_{co}$  (accompanying a rearrangement of the CO /OO state; Ln = Eu, Sm, and Sm<sub>0:2</sub>Nd<sub>0:8</sub>), are not shown for clarity. No AFM transition is observed for the A-site disordered compounds.  $T_{c}$  is the Curie temperature,  $T_{co}$  the charge-ordering temperature,  $T_{g}$  the spin glass (SG) phase transition obtained from dynam ical scaling. The inset shows the temperature dependence of the resistivity of the sam plew ith Ln = Eu, Sm, Nd, and La, measured for  $_{0}H = 0$  and 7 T.

However, a FM m etallic state can be induced by application of hydrostatic pressure [8]. LnBMO samples with larger Ln cations occupy a \critical zone" near the multicritical point of the phase diagram. For example, Nd<sub>0.5</sub>Ba<sub>0.5</sub>M nO<sub>3</sub> (NBMO) show sam etallic ground state, as well as a large CMR e ect in the vicinity of  $T_c$ . It is known that the long-range CO/OO order can be locally hindered by in purities substituting the M n-sites, as in Cr doped Pr<sub>0.5</sub>Ca<sub>0.5</sub>M nO<sub>3</sub> [4] or Nd<sub>0.5</sub>Ca<sub>0.5</sub>M nO<sub>3</sub> [5]. For Cr



FIG.2: (color online) Tem perature dependence of the width of the x-ray di use scattering around the (0 2 0) B ragg peak (in the cubic setting; shown in the left inset) in EBM 0. is estimated as the full width at half maximum of the G aussian t of [(h=0.15+ k=1.85- 0), -0.25 0.25] di use scattering pro les, as shown in the right inset.

5%, the CO/OO coherence remains concentrations on relatively large length scales, yielding separation of FM and CO/OO phases [5], and associated percolative metal-to-insulator transition upon eld application. In the present case, on the contrary, the Ln/Ba solid solution on the perovskite A-sites induces a global random ness in the potential, which breaks the CO/OO coherence down to the nanom eter scale. The short-range nature of the charge-orbital correlation is evidenced by the x-ray di use scattering [10] observed at all tem peratures in EBMO, as illustrated in Fig. 2. The intensity of the di use scattering around the (0 2 0) Bragg peak increases with decreasing tem perature, as observed in the sim ilar Ln<sub>0:55</sub>Sr<sub>0:45</sub>M nO<sub>3</sub> system [11]. The width () of the diuse scattering pro le has a relatively weak tem perature dependence, and saturates at low tem peratures around 0.16 r.l.u.. Considering a pseudocubic lattice parameter of 0.38 nm, this corresponds to a charge-orbital coherence length 2 nm . Thus, as in Ln<sub>0:55</sub>Sr<sub>0:45</sub>M nO<sub>3</sub> [11], no macroscopic phase separation is discerned, and the observed CMR e ect of  $Nd_{0.5}Ba_{0.5}MnO_3$  may reject the augmented response to magnetic elds of systems with enhanced CO/OO uctuations[9]. Away from the SG /FM phase boundary,  $Pr_{0:5}Ba_{0:5}M nO_3$  (not shown) and  $La_{0:5}Ba_{0:5}M nO_3$ (LBM O) exhibit the conventional m etallicity and m agnetoresistance around  $T_c$ , as seen in the inset of Fig. 1.

The top panel of Fig. 3 shows the tem perature dependence of the ac-susceptibility of the EBM O, SM BO and NBM O sample. As seen in the inset, the in-phase component  $^{0}(T; !)$  of the susceptibility of NBM O is typical of a FM m aterial with a sharp ferrom agnetic transition. The SBM O and EBM O instead show reduced m agne-



FIG.3: (color online) Upper panel: Tem perature (T) dependence of the out-of-phase component of the ac-susceptibility  $^{00}$ (T;!) for the compounds with Ln = Eu and Sm; h (eld am plitude) = 40e, f (= !=2, frequency) = 1.7, 17, and 170 Hz for Ln = Eu, h = 100e, f = 100, 500, 1000, and 5000 Hz for Ln = Sm. The T-dependence of the in-phase component  $^{0}$ (T;!) for Ln = Eu, Sm, and Nd is shown in inset. The frequency dependence of (T;!) of EBM O is studied in more detail in the lower panel: the T-dependence of  $^{00}$ (T;!) is shown in main frame, while  $^{0}$ (T;!) is shown in inset; h = 4 O e, f = 1.7, 5.1, 17, 51, 170, 510, 1700, and 5100 Hz. The left inset shows the dynamical scaling of (T<sub>f</sub>) = t<sub>obs</sub> with the reduced tem perature for T<sub>g</sub> = 42 K, z = 7.6 and 0 1.7 10 <sup>13</sup> s.

tization and broad transitions, sim ilar to those of disordered system s. The out-of-phase component (T;!)of the susceptibility shows no frequency dependence at the onset of FM in the case of NBMO. In SBMO and EBMO, as shown in the main frame of Fig. 3,  $^{00}(T;!)$ exhibits a fairly large f-dependence. (T;!) is recorded in a small ac magnetic eld, allowing us to probe the system (and its dynam ics) without a ecting it; the linear response of the system was con med. We analyze in detail the T - and f-dependence of  $^{(0)}(T;!)$  of EBM O shown in the lower panel of Fig. 3.  $Eu^{3+}$  is smaller than  $\text{Sm}^{3+}$ , so that EBMO is conveniently away from the phase boundary, and Eu has no large 4f m om ent affecting (T;!). The peak observed in (T;!) at all f is relatively sharp, which suggests that the system homogeneously undergoes a phase transition. Each fre-



FIG.4: (color online) Upper panel: O ut-of-phase component of the ac-susceptibility vs tem perature, measured on continuous cooling (thin line), and including two halts at  $T_{h1} = 30$  K and  $T_{h2} = 20$  K (thicker line). The inset shows the relaxation of  $^{\circ0}$  (T;!) at constant temperatures below the glass transition of EBM O.f = 1.7 Hz, h = 40 e. Low erpanel: D i erence plots of  $^{\circ0}$  (T;!) curves measured on cooling (open symbols) and subsequent re-heating (closed symbols) including halts, subtracted with their respective references measured on continuous cooling and heating. Results of single halts at  $T_h = 30$  K and  $T_h = 20$  K are shown in the main frame, while a double memory experiment with halts at both  $T_{h1} = 30$  K and  $T_{h2} = 20$  K is shown in inset for comparison.

quency corresponds to an observation time  $t_{obs} = 1 = !$ characteristic of the measurement. One can de ne from each susceptibility curve a frequency dependent freezing tem perature  $T_f(!)$ , below which the longest relaxation time of the system exceeds tobs, and the system is out-ofequilibrium. The inset in the lower panel of Fig. 3 shows the scaling of  $(T_f) = t_{obs} w$  ith the reduced tem perature =  $(T_f (f) T_g)=T_g (T_g is the spin glass phase transi$ tion tem perature) using a conventional critical slow ingdown power-law relation [12], linear in log-log axes. A good scaling is obtained for  $T_q = 42$  1 K, z = 8 1 10<sup>131</sup> s, which indicates that the time necand o essary to reach equilibrium becom es longer and longer when approaching  $\mathrm{T_g}$  = 42 K , and the relaxation time diverges at  $T_{\alpha}$  as  $=_{0} = z^{2}$ . z and are critical exponents, and 0 represents the microscopic ipping time of the uctuating entities, which in the present case is close to that of the microscopic spin ip time (10  $^{13}$  s).

The value of the product z is sim ilar to those of ordinary atom ic SG [13]. This indicates that LnBM O crystals with small Ln cations undergo a true spin glass phase transition [14], and that the low tem perature SG phase is hom ogeneously disordered, down to the nanom eter scale. This can be expected considering that without quenched disorder, the long range CO /OO state consists of ferrom agnetic zigzag chains running along the [110] direction (cubic setting) which are coupled antiferrom agnetically (so-called CE-type) [15]. Thus, in this uniform ely disordered case, the fragm entation of the zigzag chains down to the nanom eter scale (as revealed by the x-ray di use scattering) causes the mixture of AFM and FM bonds on these near atom ic length scales.

EBM 0 exhibits dynam ical features typical of SG, such as aging, memory, and rejuvenation. These phenom ena can be observed em ploying speci c cooling protocols while recording (T;!), and explained using a convenient real space picture known as the droplet model[16, 17]. In the droplet model, the slow dynamics is related to the slow rearrangement of domain walls of the SG phase by thermal activation. After a quench from the paramagnetic phase into the spin-glass phase the system is trapped in a random non-equilibrium spin con guration which slow ly equilibrates or ages. This is illustrated in the top panel of Fig. 4. As seen in inset,  $^{(0)}(T;!)$  decreases with time at constant temperature, after a quench from a reference tem perature above T<sub>q</sub>. This re ects the aging process, in which the number of droplets of relaxation time 1=! (probed by the ac-excitation of frequency !) decays as equilibrium domains are growing. The aging is also observed if, as shown in the main frame of Fig. 4, <sup>(0)</sup>(T;!) is recorded against tem perature perform ing halts during the cooling.  $^{\circ\circ}$  (T;!) is recorded vs tem perature on cooling and heating, either continuously changing the tem perature (reference curves), as well as making a halt for  $t_h = 6000 \text{ s at } T_h = 30 \text{ K or for } t_h =$ 18000 s at  $T_h = 20$  K (single memory experiments), or for both  $t_{h1}$  = 6000 s at  $T_{h1}$  = 30 K , and  $t_{h2}$  = 18000 s at  $T_{h2} = 20K$  (double m em ory experim ents). The cooling (heating) curves measured while (after) perform ing the halts are subtracted from their corresponding reference curves, and plotted in the bottom panel of Fig. 4.

 $^{\odot}(\text{T};!)$  relaxes dow nw ard at  $T_{h1}$  and  $T_{h2}$ . These agings are recovered on re-heating, as the spin con guration established during the equilibration is frozen-in upon cooling below  $T_h$ , and only a ected on short length-scales during the re-heating[17]. In other words, the system s keeps mem ory of the larger dom ains equilibrated during the halt. However, the equilibrium con gurations at distinct tem peratures are sim ilar only on short length scales, inside a so-called overlap[17] region. The mem ory of the equilibration at  $T_h$  is thus observed only in a nite tem – perature range around  $T_h$ , de ning  $\backslash mem$  ory dips" with a nite width in the di erence plots shown in the bottom panelofF ig.4.0 utside this tem perature range,  $^{\odot}(\text{T};!)$ 

recovers its reference level and the system is rejuvenated. Paradoxically[17], the domain state equilibrated during the halt at  $T_{\rm h}$  =  $T_{\rm h1}$  survives the spin recon guration occurring during a second halt at  $T_{\rm h2}$  <  $T_{\rm h1}$  on shorter length scales, an two memory dips are observed at  $T_{\rm h1}$  and  $T_{\rm h2}$ , as seen in the lower panel of Fig.4.

In summary, we have studied A-site disordered Ln<sub>0:5</sub>Ba<sub>0:5</sub>M nO<sub>3</sub> single crystals near the spin glass insulator/ferrom agnetic m etal phase boundary, located near Ln = Sm. Analyses of X-ray di use scattering and ac-susceptibility measurements reveal that the crystals with smallbandwidth behave like canonical atom ic spin glasses, and suggest a short-range orbital order and glassy spin state hom ogeneous down to the nanom eter scale. This indicates that the phase separation occurs only in crystal with local defects or impurities (such as B-site dopants), or equivalently, that no phase separation on a m icron-scale occurs in high-quality single crystals, when Ln and Ba are ordered or otherwise perfectly disordered, by no or uniform random potential. In the latter case, the spin and orbital con gurations constitute a perfect matrix for the CMR e ect to originate in, as illustrated by the gigantic response to magnetic elds of the narrow bandwidth crystals.

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